## **Supplementary Information**

## Microwaves-induced epitaxial growth of urchin-like MIL-53(AI) crystals on ceramic supports

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The ALD reactor chamber contains a heated circular sample holder ( $\emptyset = 83 \text{ mm}$ ) that can accommodate samples up to 10 mm high ( $V_{chamber} = 54 \text{ cm}^3$ ). Five pieces of SiC foams (0.5 x 1.5 x 1.5 cm) were introduced simultaneously into the reactor chamber for alumina deposition. The chamber was connected to an Ar line, precursor vessels and to a rotary pump to achieve a pressure of  $\sim 10^{-2}$  mbar. The injection of precursors was regulated by the aperture time of the precursor vessels, controlled by automatic valves. The introduction pressures of trimethylaluminum and H<sub>2</sub>O were 10 mbar and 30 mbar respectively.



Figure S1: Schematic of the home-made ALD set-up developed for Al<sub>2</sub>O<sub>3</sub> deposition (Octavio Graniel Tamayo, Atomic layer deposition for biosensing applications, PhD thesis- University of Montpellier-France, 2020).

Raman analysis was carried out to confirm the formation of MIL-53(AI) on SiC foam after hydrothermal synthesis by conventional or MW-assisted heating (Figure S2).

It should be noted that the foam has a very wavy surface and the amount of MIL-53(AI) relative to SiC is too low to be detected by X-ray diffraction.



Figure S2: Raman spectra of MIL-53@SiC prepared using MW-assisted heating (A) and MIL-53@SiC-CONV prepared via conventional heating (B), in comparison with the Raman spectra of MIL-53(AI) powder synthetized under MW-assisted (C) and conventional heating (D). The band around 753 cm<sup>-1</sup> corresponds to v(Si-C) of the SiC foam. The regions of spectra (A) highlighted in yellow correspond to MIL-53(AI) in which the bands of spectra A and B overlap and subsequently indicate the presence MIL-53(AI) supported on SiC. In the case of spectrum C, luminescence does not allow further interpretation of the spectrum above 1800 cm<sup>-1</sup>. Thus, the vibration bands of MIL-53(AI) prepared via conventional heating could not be observed. Moreover, via the conventional heating method, MIL-53(AI) appears less crystalized. Its spectrum (D) is less defined, making its analysis more tedious.



Figure S3: EDX mapping on the cross-section of MIL-53@SiC sample showing the dispersion of AI, C, O and Si atoms.

Compound	Dielectric	Dielectric loss ε"	Thermal conductivity	Ref
·	constant e'		(W/mK)	
Water	78.68	10.61	0.609	1,2
Al(NO₃)₃ 500 mM	58.85	64.58	-	1
Al(NO₃)₃ 5 mM	80	20	-	1
Terephathalic acid	2.53	0.03	-	1
Terephthalic in complex with cation	70-77	14-29	-	1
Al <sub>2</sub> O <sub>3</sub>	10.8	0.16	26	2
SiC	26.66	27.99	40	2
ZrO <sub>2</sub>	22.5	0.02	1.7	3

Table S1 : Dielectric properties and thermal conductivity of water, SiC,  $ZrO_2$ ,  $Al_2O_3$  and MIL-53(Al) precursors, at 2.45 GHz and room temperature. The dielectric constant is the ability to store electric charges while the dielectric loss is the capacity to transform the electromagnetic energy into heat.

1. Laybourn, A. *et al.* Understanding the electromagnetic interaction of metal organic framework reactants in aqueous solution at microwave frequencies. *Phys. Chem. Chem. Phys.* **18**, 5419–5431 (2016).

2. Samanta, S. K., Basak, T. & Sengupta, B. Theoretical analysis on microwave heating of oil-water emulsions supported on ceramic, metallic or composite plates. *Int. J. Heat Mass Transf.* **51**, 6136–6156 (2008).

3. Yi, M. *et al.* Surface-enhanced raman scattering activity of zro2 nanoparticles: Effect of tetragonal and monoclinic phases. *Nanomaterials* **11**, (2021).



Figure S4: SEM image of a sample prepared by MW-assisted conversion of a  $\gamma$ -alumina Accu<sup>®</sup>spheres into MIL-53(Al) showing 1D-directional growth of urchin-like crystals.



Figure S5: Cross-section of ALD-alumina coated SiC-foam.

Table S2: Elemental analysis result obtained by EDX of ALD-alumina coated SiC-foam in cross-section as presented in Figure
S4 showing the difference in weight percentage of C, Na, O and Al (*note that the native SiC-foam contains an aluminum
additive ~ 5 wt%).

SiC-foam	ALD-alumina coating
22.3 ± 4.5	17.6 ± 3.5
$0.5 \pm 0.1$	-
5.1*± 1.0	12.3 ± 2.5
31.7 ± 6.4	7.2 ± 1.4
	SiC-foam 22.3 ± 4.5 0.5 ± 0.1 5.1*± 1.0 31.7 ± 6.4



Figure S6:  $N_2$  adsorption/desorption isotherms for MIL-53@SiC prepared under MW-assisted heating and MIL-53@SiC-CONV prepared under conventional heating.



Figure S7: SEM images of MIL-53@SiC after adherence test, confirming good adhesion and unchanged distribution of MIL-53(AI) crystals on the ceramic supports.

Table S3: Results of sonication stability tests- Comparison of average aluminum concentration (EDX analysis- wt%) and sample mass variation before and after sonication.

	[AI] <sub>EDX</sub> wt%	[Al] mass variation (wt%)
Before sonication	5.00 ± 0.5	-
After 15 min sonication	4.60 ± 0.5	- 0.40
After 60 min sonication	4.58 ± 0.5	- 0.42



Figure S8: SEM images of pristine ZrO<sub>2</sub> foam (a) and MIL-53(AI) crystals grown on ZrO<sub>2</sub> foam by conversion of ALD-alumina (b, c) using the same synthesis procedure as for MIL-53@SiC. The ZrO<sub>2</sub> foams with 10 ppi were supplied by EPMF-France (reference: STELEX-ZrO2-10 PPI).

The nature of the ceramic support does not influence the textural properties of the formed MIL-53(AI) crystals. Indeed, the specific surface areas ( $S_{BET}$ ) and pore volumes ( $V_p$ ) measured for MIL-53(AI) grown on ZrO<sub>2</sub> and SiC were very similar (Table S4).

Table S4 : Comparison of the textural characteristics measured for MIL-53(AI) grown on SiC and  $ZrO_2$  ceramic foams and extrapolated to the MIL-53(AI) material- Values of  $S_{BET}$  and pore volume ( $V_p$ ) were attributed to the sole contribution of the MOF material (An error of ~10% is estimated for  $S_{BET}$ ,  $V_p$  values)

Sample	Δm	S <sub>BET</sub>	Vp	S <sub>BET</sub> (MIL-53(AI))	V <sub>p</sub> (MIL-53(Al))
	(wt%) <sup>*</sup>	(m²/g)	(cm³/g)	(m²/g)	(cm³/g)
MIL-53@ZrO₂	1.1 %	1	0.002	91	0.182
MIL-53@SiC	9.1 %	7	0.019	80	0.200

 $\Delta m = m_{(sample after conversion)} - m_{(pristine foam)}$ 

	∆m (wt%)ª	S <sub>BET</sub> V <sub>r</sub> (m²/g) (cm³	V <sub>p</sub>	Formed material	S <sub>BET</sub> (formed material) (m²/g)	V <sub>p</sub> (formed material) (cm <sup>3</sup> /g)
			(cm³/g)			
As prepared in this work MIL- 53@SiC	9.1%	7	0.019	MIL-53(AI)	80	0.200
After calcination	2.7 %	8	0.024	$AI_2O_3$	298	0.926
	3.5 % <sup>b</sup>				227*	0.681*

Table S5 : Impact of thermal treatment of MIL-53@SiC (3h at 1000°C - 5°C/min- in air) on its textural characteristics. a.  $\Delta m = m$ (thermal treated MIL-53@SiC)- m(foam) b. wt% of Al<sub>2</sub>O<sub>3</sub> determined by EDX. c. Mean pore size values at maximal distribution intensity. \*S<sub>BET</sub> and V<sub>p</sub> determined by considering the wt% of the formed material (Al<sub>2</sub>O<sub>3</sub>) determined by EDX. (An error of ~10% is estimated on the S<sub>BET</sub> Vp).



Figure S9: (a) PXRD diffraction pattern of  $AI_2O_3$  obtained after calcination of MIL-53(AI) at 1000°C in air. Since XRD analysis was not feasible on foam samples, MIL-53(AI) was directly grown on 1g boehmite powder (Sasol) using the same synthesis conditions. The pattern was recorded with a Malvern Panalytical X'Pert Powder S using a scan rate of 0.021°/s. Diffractogram was analyzed with the software X'Pert Highscore Plus. Based on phase analysis (b), a major theta alumina phase and a minor corundum (alpha) alumina phase were determined with the respective proportion of 90% and 10% respectively.